



# RD\_Fase2 Pixel

*G. Darbo*  
*Vidyo, 11 July 2014*



*CSN1 funds*

*CSN5 project*

*EU funds: AIDA-2*

*Indico agenda:*

<https://agenda.infn.it/conferenceDisplay.py?confId=8380>

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# 2014 – FUNDING AND STATUS



# Got Funded (ATLAS + COMMON)

## 3D Sensors

- Funded 3 batches at FBK:
  - Mechanical test – approved by MEMS3 committee – order placed (3x2200 €)
  - Simple planar to qualify substrates – approved by MEMS3 – order placed (6x2200 €)
  - 3D batch, single side, on hold waiting batch 2.
- Substrates
  - Ordered 55 wafers from IceMOS (SiSi wafer bonded) – material arrived at CERN, reshipped to TN
  - Looking for Epi wafers – indirect contact with SHINETSU – offer received (25 wafers – 11.9 kCHF) – doubts on specifications (epi-layer thickness spread: 104÷156 µm!)

## Bump-bonding

- Funded 20 k€ for BB at Selex + 7 k€ for FE-I4B
  - Bump-bond 3D sensors in production at FBK – old design IBL-like
  - Develop Indium-bumps for high density – incomplete funding: cut the dummy wafers (6 k€) and funds for Selex (10 k€).

## HV-CMOS hybridization

- FE-I4B plus consumables to test hybridization

## CO2 cooling

- Funded TRACI CO2 cooler

## SUMMARY OF RECEIVED FUNDS IN 2014

Date	Sezione	Category	ATLAS/COMMON	Assigned	Committed	Description
Feb 2014	GE	3D	COMMON	€ 21 000	€ 15 000	Wafer for 3D sensors (common with CMS) -
Apr 2014	GE	3D	COMMON	€ 44 000	€ 19 800	3 processes at FBK - 2 committed
May 2014	GE	HV	ATLAS	€ 13 000		HV-CMOS Hybridization - 3 FE-I4B wafers
May 2014	MI	BB	ATLAS	€ 27 000		BB of 3D (IBL design on 6") + BB high density + 3 FE-I4B wafers
May 2014	MI	CO2/µ-CH	ATLAS	€ 20 000		TRACI - co-funded with LHCB
				<b>€ 125 000</b>		

*How to prepare 2015 fund requests – few tables to keep in mind*

# **CSN1 – FUNDS 2015**



# ATLAS / CMS Pixel R&D – Cost Profile

Richieste CSN1 (17/3/2014) - 2014, 2015, 2016

Attività	Descrizione	2014	2015	2016	Total	Grand T.	ACTIVE	Nota
3D	ATLAS	k€ -	k€ -	k€ -	k€ -			4 batches: (1) mechanical test (3 litho), (2) substrate test with planar (6 litho), 3D batch 1 (11 litho), 3D batch 2 (11 litho - 2016 in MEMS3), SiS DWB / Sol /Epi
3D	CMS	k€ -	k€ -	k€ -	k€ -			
3D	Common	k€ 64.0	k€ 20.0	k€ 24.2	k€ 108.2	k€ 227.2	k€ 195.8	
AE	ATLAS	k€ -	k€ -	k€ -	k€ -			2 batches: 2015 - 2016. Both in MEMS3, substrates, thinning. Partially in ACTIVE (1 batch)
AE	CMS	k€ 32.0	k€ 20.0	k€ 67.0	k€ 119.0			
AE	Common	k€ -	k€ -	k€ -	k€ -			
HV	ATLAS	k€ 62.5	k€ 100.0	k€ 50.0	k€ 212.5			
HV	CMS	k€ -	k€ -	k€ -	k€ -	k€ 212.5	k€ -	
HV	Common	k€ -	k€ -	k€ -	k€ -			
BB	ATLAS	k€ 37.5	k€ -	k€ -	k€ 37.5			Upgrade for 6" at selex, 3D/Active module bumping, develop hi-density and thin BB.
BB	CMS	k€ 27.0	k€ 24.0	k€ 64.0	k€ 115.0	k€ 324.5	k€ 227.4	
BB	Common	k€ 36.0	k€ 48.0	k€ 88.0	k€ 172.0			
MOD	ATLAS	k€ 11.0	k€ 20.0	k€ -	k€ 31.0			-> FE-I4 test upgrade, flex, module assy, contr. to TB -> Setup, module assy, TB setups, shipping, sample prep. -> Irradiation
MOD	CMS	k€ 10.0	k€ 42.0	k€ -	k€ 52.0	k€ 147.0	k€ 165.0	
MOD	Common	k€ -	k€ -	k€ 64.0	k€ 64.0			
M-R/O	ATLAS	k€ -	k€ 15.0	k€ 20.0	k€ 35.0			Board per R/O fino a 16 FE-I4, test infiniband/GBT/Felix,etc. - 2 prototipi + 5 schede per lab italiani
M-R/O	CMS	k€ -	k€ -	k€ -	k€ -	k€ 35.0	k€ -	
M-R/O	Common	k€ -	k€ -	k€ -	k€ -			
CO2/μCH	ATLAS	k€ 20.0	k€ 20.0	k€ 20.0	k€ 60.0			
CO2/μCH	CMS	k€ 20.5	k€ 14.5	k€ 23.3	k€ 58.3	k€ 118.3	k€ 171.0	
CO2/μCH	Common	k€ -	k€ -	k€ -	k€ -			
Tot	ATLAS	k€ 131	k€ 155	k€ 90	k€ 376			
Tot	CMS	k€ 90	k€ 101	k€ 154	k€ 344	k€ 1065	k€ 759	
Tot	Common	k€ 100	k€ 68	k€ 176	k€ 344			
		<b>k€ 321</b>	<b>k€ 324</b>	<b>k€ 421</b>				

Goes to CSN5

Stays in CSN1

**Legend:**

- 3D 3D sensor batches and raw wafers
- AE AE sensor batches and raw wafers
- HV HV-CMOS development: contribution to MPW and module integration
- BB Bump-bonding for module and sensor testing, BB development for hi-density and thin modules
- MOD Module dressing with flex/PCB, irradiation, test-beam
- M-R/O Multi module R/O for test beam an test system
- CO2 CO2 cooling (μCH or Standard)
- μ-CH μ-channel cooling development

# Referee CSN1: Tasca + CSN5

## Richieste

		2014-2017			2014			
		ATL	CMS	Com	ATL	CMS	Com	
tracker	3D			108			64	
	AE		119			32		
	HV	212			62			
	BB	37	137	142	37	27	6	
	MOD	31	52	128				
	Mod R0	37						
	cooling	60	60.5		20	20.5		ATL-sinergia LHCb / CMS PI
	<b>Totali</b>	<b>377</b>	<b>368.5</b>	<b>378</b>	<b>119</b>	<b>79.5</b>	<b>70</b>	
		1123.5			268.5			

## Proposte

		2014-2017			2014			CALL			
		ATL	CMS	Com	ATL	CMS	Com	ATL	CMS	Com	
tracker	3D			108			65				
	AE		80			32					ipotizziamo che continui mems3
	HV				13			212			
	BB	37	137	142	27	27					
	MOD	31	52	128							
	Mod R0	25									ridurre il numero sedi dove fare test.
	cooling	40	40		20	10					
	<b>Totali</b>	<b>133</b>	<b>309</b>	<b>378</b>	<b>60</b>	<b>69</b>	<b>65</b>	<b>212</b>	<b>0</b>	<b>0</b>	
		820			194			212			

# What Anticipated for 2015 to CSN1

The table below follows the document provided to referee in March and later updated in May.

- In preparing the request for 2015 should be coherent with that

## Considerations

- Should revise the numbers below with better cost estimation, but stay in the envelopes ("tasca") defined by CSN1 in May

### Richieste CSN1 - 2015: ATLAS + COMMON ("WHAT CSN1 KNOWS")

Attività	Descrizione	Richiesta	ATLAS	50-50	% ATLAS	Sez. Assegn.	Nota
3D.1	6" Wafer procurement (SOI, wafer bonding, epi)	k€ 20.0		k€ 20.0	50%	XX/CMS	Substrates for 2nd 3D batch (batch 5)
BB.1	6" dummy wafers - test deposition on 6" and high-density bumps (150 k-bumps/chip)	k€ 6.0		k€ 6.0	50%	XX/CMS	6k€ for dummy wafer with resistive chains + mask for In deposition.
BB.2	BB for 3D sensor test	k€ 48.0		k€ 48.0	50%	XX/CMS	To be done at Selex or IZM, when FBK 3D sensors (batch 3) are available. In spring 2015 - Mask (1), FE Wafer (4: FE-I4 and PSI46), 3D wafers (8), Flip-chip (60)
<b>Total requested by ATLAS</b>		<b>k€ 120.0</b>	<b>k€ 46.0</b>	<b>k€ 74.0</b>			

## Funding must follow timeline

WP	Date	Milestones - V1 (to be agreed with CMS)
3D	30/06/2014	Selection and procurement of the raw wafers
	30/11/2014	Qualifica dei substrati da usare per i sensori 3D
	30/11/2015	3D sensor of batch 1 measured in laboratory and test beam with FE-I4/PSI46 chips
	30/11/2016	3D sensor of batch 2 produced
HV/MOS	30/09/2014	Design-1 ready to submit
	30/09/2015	Measurements of design 1 in lab and test-beam performed
	30/06/2015	Hybridization process qualified
	30/11/2015	Design-2: full scale chip
	30/09/2016	Design-2: qualified at lab and test-beam
Bump-bonding	30/09/2014	Test of single side bumps completed
	30/09/2015	3D of batch 1 bumped to FE-I4/PSI46
	30/06/2015	Results of high density bumps - technology review
CO <sub>2</sub> /μ-CH	30/09/2014	TRACI: operational
	30/09/2015	Qualification of thermal behaviour of staves with cooling channel
M-Mod R/O	30/11/2015	Prototype of M-module R/O board available and tested
	30/06/2016	5 M-Module R/O boards produced.

Buy substrates for 2<sup>nd</sup> batch

Funds needed for BB  
 Funds needed to develop HD BB

Develop μ-CH cooling

Funds for prototype



# EU FUNDS- AIDA-2



# Silicon in AIDA2: Beneficiaries

## WP3:

Electronics & Interconnections

### AIDA 2 - WP Name - Task 3.2: 65 nm chips

Beneficiary short name*	Institute
CERN	CERN
INFN	PAVIA
INFN	TORINO
INFN	MILANO
IN2P3	CPPM
IN2P3	OMEGA/LAL/LPNHE
AGH	AGH-Krakow

### AIDA 2 - WP Name - Task 3.3: SiGe chips

Beneficiary short name*	Institute
IN2P3	OMEGA
IN2P3	CPPM
CEA	SACLAY
AGH	AGH-Krakow
UHEIDELBERG	University of Heidelberg

### AIDA 2 - WP Name - Task 3.4: Interconnection and TSV

Beneficiary short name*	Institute
INFN	PAVIA
INFN	GENOVA
INFN	PERUGIA
IN2P3	CPPM
IN2P3	LAL
UBONN	University of Bonn
UU	University of Uppsala
UGLAS	University of Glasgow
MPG	MPI Munich

## WP5:

Advanced Hybrid Pixel Detectors

### AIDA 2 - WP Name - Task 5.2: TCAD SIMULATION

Beneficiary short name*	Institute
INFN	Perugia
INFN	Trento
CERN	LCD

### AIDA 2 - WP Name - Task 5.3: Process optimization

Beneficiary short name*	Institute
CSIC	CNM
FBK	

### AIDA 2 - WP Name - Task 5.4: Detector validation (3D and planar sensors)

Beneficiary short name*	Institute
CERN	LCD
MPG	MPP
Manchester	
INFN	Milano
INFN	Firenze

## WP6:

HV/HR-CMOS

ATLAS – Beneficiary

CMS – Beneficiary

### AIDA 2 - HV-CMOS - Task 6.2: Simulation

Beneficiary short name*	Institute
CPPM	Marseille
Bonn	
STFC	RAL

### AIDA 2 - HV-CMOS - Task 6.3: Sensor development

Beneficiary short name*	Institute
Bonn	
KIT	Karlsruhe
CEA	Saclay
STFC	RAL
Glasgow	
Liverpool	
CPPM	Marseille

### AIDA 2 - HV-CMOS - Task 6.4: Hybridisation

Beneficiary short name*	Institute
IFAE	Barcelona
Liverpool	
INFN	Genova